

SRM Institute of Science and Technology College of Engineering and Technology

DEPARTMENT OF ECE

SRM Nagar, Kattankulathur – 603203, Chengalpattu District, Tamilnadu

SET B

OFFLINE MODE

Academic Year: 2021-2022 (EVEN)

Test: CLAT- 1 Date: 07-04-2022 Course Code & Title: 18ECC201J - Analog Electronic Circuits **Duration:** 60 minutes Year & Sem: II / IV Max. Marks: 25

| C | | 42 | 1 ~ 4 2 ~ ~ ~ | Matrix: | |
|--------|---------------|------|---------------|---------|--|
| Course | \mathcal{A} | rucu | iauon | Matrix: | |

| | 18ECC201J - Analog Electronic Circuits | Program Outcomes (POs) | | | | | | | | | | | | | | |
|-----------|---|------------------------|-------------------------|---|---|---|-----|-----|-----|-----|-----|-----|-----|-----|---|---|
| | | | Graduate Attributes PSC | | | | | | PSO | | | | | | | |
| COs | Course Outcomes (COs) | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 1 | 2 | 3 |
| CO-1 : | Analyze bipolar amplifier circuits and their frequency response. | 1 | 2 | 3 | - | - | - 1 | - | ı | - 1 | - 1 | ı | - 1 | - 1 | - | - |
| CO-2 : | Develop MOSFET amplifier circuits and their frequency response. | 1 | 2 | 3 | - | - | 1 | - | 1 | 1 | 1 | 1 | 1 | - 1 | - | - |
| CO-3 : | Compile various negative feedback amplifier and oscillator circuits. | 1 | - | 3 | - | - | - | - | - | - | - | - | - | 1 | - | - |
| CO-4 : | Demonstrate the different classes of power amplifiers according to their performance characteristics. | 1 | 2 | 3 | - | - | - 1 | - 1 | - 1 | - 1 | 1 | - 1 | 1 | - 1 | - | - |
| CO-5 | Construct the basic circuit building blocks that are used in the design of IC amplifiers, namely current mirrors and sources. | 1 | 2 | 3 | - | - | - 1 | - | 1 | - 1 | - | 1 | - | 1 | - | - |
| | Organize analog electronic circuits using discrete components to measure various analog circuits' performance. | 1 | - | 3 | - | - | - 1 | - | - 1 | 2 | 1 | - 1 | 1 | 3 | 1 | - |

Part - A $(5 \times 1 = 5 \text{ Marks})$ **Instructions: Answer any 5**

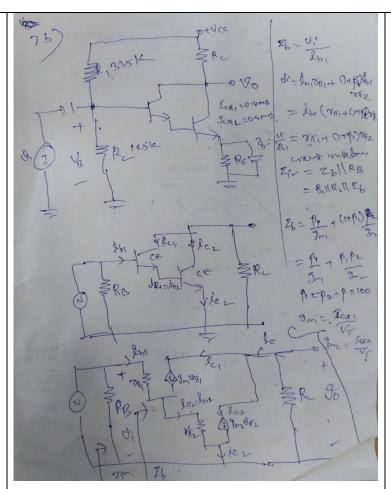
| Q. No | Question | Mar | BL | CO | PO | PI |
|-------|--|-----|----|----|----|------|
| | | ks | | | | Code |
| 1 | b. that I _C flows into transistor while I _E flows out it | 1 | 1 | 1 | 1 | |
| 2 | d. 0.002 mA | 1 | 3 | 1 | 2 | |
| 3 | d. Cascode | 1 | 1 | 1 | 1 | |
| 4 | a. Saturation point and Cutoff point | 1 | 2 | 1 | 1 | |
| 5 | c Stray | 1 | 3 | 1 | 2 | |

Part - B

| | $(2 \times 10 = 20 \text{ Marks})$ | | | | | |
|----|--|---|---|---|---|--|
| | Instructions: Answer any TWO | | | | | |
| 6. | For the circuit given below with transistor parameters | | | | | |
| | $I_{CEQ} = 2.79 \text{ mA}, \beta = 180 \text{ and } r_0 = \infty,$ | | | | | |
| | a. Determine the Q point values. (4) | 5 | 3 | 1 | 3 | |
| | b. Find the small signal parameters and voltage gain incluing the source resistance (R _S). (6) | 5 | 2 | 1 | 2 | |
| | $V^{+} = +5 \text{ V}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ $R_{C} = \begin{cases} R_{C} = 1 \text{ k}\Omega \end{cases}$ | | | | | |

| | 6. Q point values (2 leg, Vcaq) (a) Given Leg = 2.7mA, B= 180 . 4 %= 20 Year = Vec. Te (Re +Re) 5 = 3.0646 = 1.394V. (a) point = (2.79mAg 1.394V) B small signal parameters. 9m = Lea : 2.79 = 102.3mN/V Vy 0.026 Ny = BV7 = 180×0.026 = 1.67 ks. Dea 2.79 Q : Rylley lib 1) = Ny + (HB) Re = 1.67 + 18.1 = 19.77 ks. = 1.2× 19.77 = 1.131k2 1.2+ 19.77 - Ay = - B. Re Ny + ((HB) Re Q+Ri (: Ay = -7.89) | | | | | |
|-----|--|---|---|---|---|--|
| 7.a | Draw the Darlington amplifier and derive the expression for the current gain and input resistance. $ \begin{array}{cccccccccccccccccccccccccccccccccc$ | 5 | 2 | 1 | 3 | |

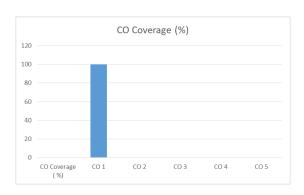
| | INPUT RESISTANCE $R_{i} = \frac{V_{i}}{T_{i}}$ $V_{i} = V_{i}, + V_{i}$ $V_{i} = \frac{T_{i}}{T_{i}}$ $V_{i} = \frac{T_{i}}{T_{i}} + \frac{T_{i}}{T_{i}} \cdot V_{i}$ $= \frac{T_{i}}{T_{i}} + \frac{T_{i}}{T_{i}} \cdot V_{i}$ $= \frac{T_{i}}{T_{i}} \cdot V_{i} \cdot T_{i}$ $= \frac{T_{i}}{T_{i}} \cdot$ | 5 | 3 | 1 | 3 | |
|------|---|---|---|---|---|--|
| 7.b. | Determine the value of input resistance for the given circuit. Assume $\beta = 100$; $I_{C1} = I_{C2} = 4$ mA. | | | | | |
| | | | | | | |

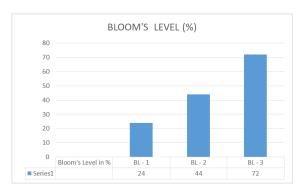


| 8.a. | Why common collector configuration is otherwise called as Emitter Follower? Common-collector transistor amplifiers are so-called because the input and output voltage points share the collector lead of the transistor in common with each other, not considering any power supplies. The common-collector amplifier is also known as an emitter-follower. (2) | 2 | 2 | 1 | 2 | |
|------|--|---|---|---|---|--|
| 8.b. | Derive the output resistance for a common collector configuration with necessary diagram # Output Impedance (Ro) The independent voltage source is set to zero ($V_3=0$). A test vorage V_n is applied to the olp terminals and the resulting test current is T_n $R_n = V_n$ $R_n = V_n$ $R_n = V_n$ $R_n = V_n + V_n$ | 8 | 3 | 1 | 3 | |

In = $V_{R_{E}}$ + $\frac{1}{20}$ +

Course Outcome (CO) and Bloom's level (BL) Coverage in Questions





Approved by the Course Coordinator